

Trench Schottky Rectifier, Very Low Leakage

NRVTSS5100E, NRVTSAF5100E

Features

- Fine Lithography Trench-based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- High Surge Capability
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free and Halide-Free Devices

Typical Applications

- Switching Power Supplies including Wireless, Smartphone and Notebook Adapters
- High Frequency and DC-DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation
- LED Lighting

Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in.
- Lead Finish: 100% Matte Sn (Tin)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

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• Device Meets MSL 1 Requirements

SCHOTTKY BARRIER RECTIFIERS 5 AMPERES 100 VOLTS





SMB CASE 403A

SMA-FL CASE 403AA STYLE 6

MARKING DIAGRAMS





A = Assembly Location
Y = Year
WW = Work Week

WW = Work Week
■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100	V
Average Rectified Forward Current (T _L = 100°C)	I _{F(AV)}	5.0	А
Peak Repetitive Forward Current, (Square Wave, 20 kHz, T _L = 83°C)	I _{FRM}	10	А
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	50	А
Storage Temperature Range	T _{stg}	−65 to +175	°C
Operating Junction Temperature	TJ	-55 to +175	°C
ESD Rating (Human Body Model)		1B	
ESD Rating (Charged Device Model)		> 1000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic			Max	Unit
Maximum Thermal Resistance, Steady State (Note 1)				°C/W
(NRVTSAF5100E) Junction-to-Lead		$R_{ heta JL}$	25	
	Junction-to-Ambient	$R_{ heta JA}$	90	
(NRVTSS5100E)	Junction-to-Lead	$R_{ heta JL}$	13.1	
	Junction-to-Ambient	$R_{ heta JA}$	71.1	

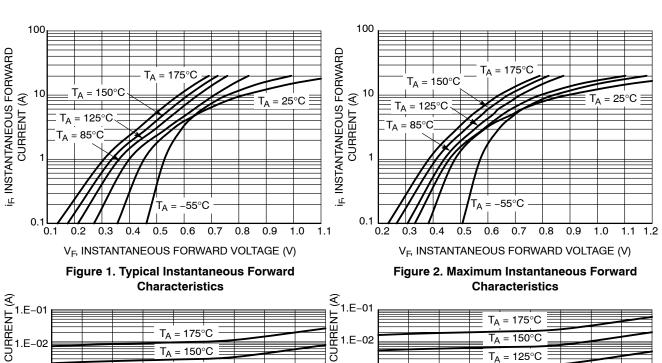
^{1.} Assumes 600 mm² 1 oz. copper bond pad, on a FR4 board

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Тур	Max	Unit
Instantaneous Forward Voltage (Note 2)	٧F			V
$(i_F = 3.0 \text{ A}, T_J = 25^{\circ}\text{C})$		0.56	-	
$(i_F = 5.0 \text{ A}, T_J = 25^{\circ}\text{C})$		0.65	0.69	
(i _F = 3.0 A, T _{.I} = 125°C)		0.50	-	
$(i_F = 5.0 \text{ A}, T_J = 125^{\circ}\text{C})$		0.56	0.62	
Reverse Current (Note 2)	i _R			
(Rated dc Voltage, T _J = 25°C)		2.6	29	μΑ
(Rated dc Voltage, T _J = 125°C)		2.2	5	mA
Diode Capacitance	C _d			pF
(Rated dc Voltage, T _J = 25°C, f = 1 MHz)		54.4		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

TYPICAL CHARACTERISTICS



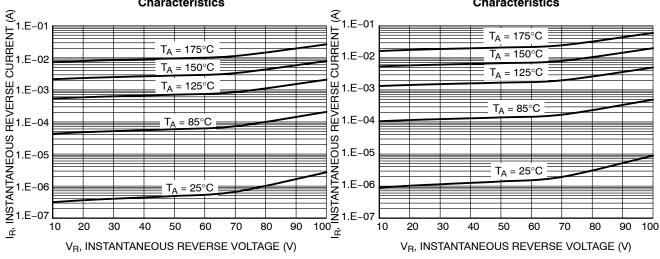


Figure 3. Typical Reverse Characteristics

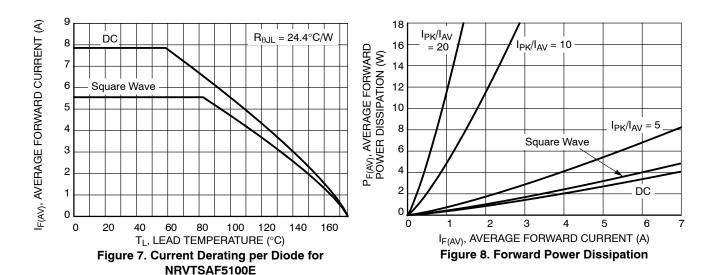
1000 F(AV), AVERAGE FORWARD CURRENT (A) 9 DC 8 C, JUNCTION CAPACITANCE (pF) 7 6 Square Wave 5 100 3 $R_{\theta JL}$ = 13.1°C/W 0 0.1 10 20 40 60 80 100 120 160 V_R, REVERSE VOLTAGE (V) T_L, LEAD TEMPERATURE (°C)

Figure 5. Typical Junction Capacitance

Figure 6. Current Derating per Diode for NRVTSS5100E

Figure 4. Maximum Reverse Characteristics

TYPICAL CHARACTERISTICS



1000 100 50% Duty Cycle 20% R_(t), (°C/W) 10% 🗒 10 5% # 2% 1% 0.1 0.000001 0.00001 0.0001 0.001 0.01 0.1 10 100 1000 1 t, PULSE TIME (S)

Figure 9. Transient Thermal Response, Junction-to-Ambient, for NRVTSS5100E

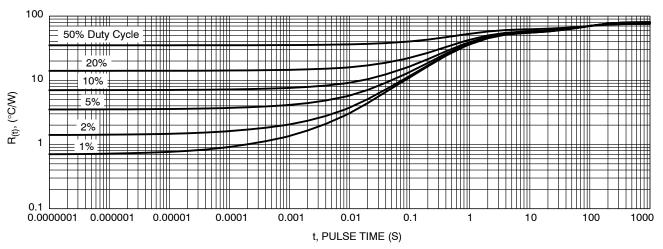


Figure 10. Transient Thermal Response, Junction-to-Ambient, for NRVTSAF5100E

ORDERING INFORMATION

Device	Package	Shipping [†]
NRVTSAF5100ET3G	SMA-FL (Pb-Free)	5000 / Tape & Reel
NRVTSS5100ET3G	SMB (Pb-Free)	2500 / Tape & Reel
NRVTSS5100ET3G-GA01	SMB (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.



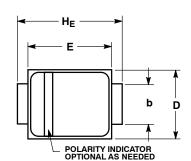


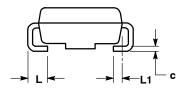
SMB CASE 403A-03 **ISSUE J**

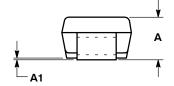
DATE 19 JUL 2012

SCALE 1:1 **Polarity Band**

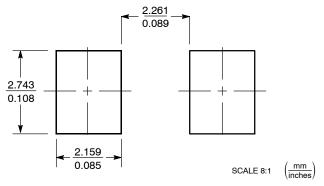
Non-Polarity Band







SOLDERING FOOTPRINT*

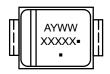


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCL.
- 3. DIMENSION b SHALL BE MEASURED WITHIN DIMENSION L1.

	MILLIMETERS				INCHES	
DIM	MIN	NOM	MAX	MIN	MOM	MAX
Α	1.95	2.30	2.47	0.077	0.091	0.097
A1	0.05	0.10	0.20	0.002	0.004	0.008
b	1.96	2.03	2.20	0.077	0.080	0.087
С	0.15	0.23	0.31	0.006	0.009	0.012
D	3.30	3.56	3.95	0.130	0.140	0.156
E	4.06	4.32	4.60	0.160	0.170	0.181
HE	5.21	5.44	5.60	0.205	0.214	0.220
L	0.76	1.02	1.60	0.030	0.040	0.063
L1		0.51 REF			0.020 REF	

GENERIC MARKING DIAGRAM*





Polarity Band

Non-Polarity Band

XXXXX = Specific Device Code = Assembly Location Α

= Year WW = Work Week = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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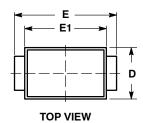
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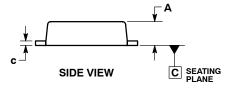


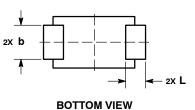


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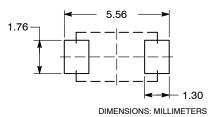


NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.90	1.10	
b	1.25	1.65	
С	0.15	0.30	
D	2.40	2.80	
Е	4.80	5.40	
E1	4.00	4.60	
_	0.70	1 10	

RECOMMENDED SOLDER FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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